IOPscience

Table of contents

Nanotechnology

Volume 24

Number 38, 27 September 2013

« previous

Special issue on synaptic electronics

(http://oas.iop.org/5c/iopscience.iop.org/1747944028/Middle/default/empty.gif/714a5a4a5031496f4154634141334358?x)

Editorial

Topical review

Tutorial

Papers

384004 A theoretical and experimental study of neuromorphic atomic switch networks for reservoir computing Henry O Sillin, Renato Aguilera, Hsien-Hang Shieh, Audrius V Avizienis, Masakazu Aono, Adam Z Stieg and James K Gimzewski doi:10.1088/0957-4484/24/38/384004 (http://dx.doi.org/10.1088/0957-4484/24/38/384004) Abstract References Supplementary data

384005 Short-term memory of TiO_2-based electrochemical capacitors: empirical analysis with adoption of a sliding threshold Hyungkwang Lim, Inho Kim, Jin-Sang Kim, Cheol Seong Hwang and Doo Seok Jeong doi:10.1088/0957-4484/24/38/384005 (http://dx.doi.org/10.1088/0957-4484/24/38/384005) Abstract References

384006 Volatile and nonvolatile selective switching of a photo-assisted initialized atomic switch T Hino, T Hasegawa, H Tanaka, T Tsuruoka, K Terabe, T Ogawa and M Aono doi:10.1088/0957-4484/24/38/384006 (http://dx.doi.org/10.1088/0957-4484/24/38/384006) Abstract References

384007 A generic simulator for large networks of memristive elements Zoran Konkoli and Göran Wendin doi:10.1088/0957-4484/24/38/384007 (http://dx.doi.org/10.1088/0957-4484/24/38/384007) Abstract References

384008 Compact modeling of CRS devices based on ECM cells for memory, logic and neuromorphic applications E Linn, S Menzel, S Ferch and R Waser doi:10.1088/0957-4484/24/38/384008 (http://dx.doi.org/10.1088/0957-4484/24/38/384008) Abstract References

384009 Nanoscale RRAM-based synaptic electronics: toward a neuromorphic computing device Sangsu Park, Jinwoo Noh, Myung-lae Choo, Ahmad Muqeem Sheri, Man Chang, Young-Bae Kim, Chang Jung Kim, Moongu Jeon, Byung-Geun Lee, Byoung Hun Lee and Hyunsang Hwang doi:10.1088/0957-4484/24/38/384009 (http://dx.doi.org/10.1088/0957-4484/24/38/384009) Abstract References

384010 Integration of nanoscale memristor synapses in neuromorphic computing architectures Giacomo Indiveri, Bernabé Linares-Barranco, Robert Legenstein, George Deligeorgis and Themistoklis Prodromakis doi:10.1088/0957-4484/24/38/384010 (http://dx.doi.org/10.1088/0957-4484/24/38/384010) Abstract References

384011 A scalable neural chip with synaptic electronics using CMOS integrated memristors Jose M Cruz-Albrecht, Timothy Derosier and Narayan Srinivasa doi:10.1088/0957-4484/24/38/384011 (http://dx.doi.org/10.1088/0957-4484/24/38/384011) Abstract References

384012 Spike-timing dependent plasticity in a transistor-selected resistive switching memory S Ambrogio, S Balatti, F Nardi, S Facchinetti and D Ielmini doi:10.1088/0957-4484/24/38/384012 (http://dx.doi.org/10.1088/0957-4484/24/38/384012) Abstract References

384013 Neuromorphic function learning with carbon nanotube based synapses Karim Gacem, Jean-Marie Retrouvey, Djaafar Chabi, Arianna Filoramo, Weisheng Zhao, Jacques-Olivier Klein and Vincent Derycke doi:10.1088/0957-4484/24/38/384013 (http://dx.doi.org/10.1088/0957-4484/24/38/384013) Abstract References

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